NSN 5961-01-545-8609

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View Online at https://aerobasegroup.com/nsn/5961-01-545-8609 **Inclosure Material:** Metal **Overall Height:** Between 0.670 inches and 0.710 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** Circuit card assembly **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes all primaries **Power Rating Per Characteristic:** 1.2 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Product Name:** (inavy)semiconductor devic (drawing)semiconductor device, transistor, amplifier, pnp, silicon(a3263509) **Special Features:** Operating temperature: -65 to 200 degrees celsius **Terminal Type And Quantity:** 4 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: